

SBND Photon Propagation Simulation: Semi-Analytical Model

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SBND Photon Model

- I will give an overview of the photon model/library that is used in SBND: the Semi-Analytical Photon Model
- this presentation is essentially a summary of the following paper:

Predicting transport effects of scintillation light signals in large-scale liquid argon detectors

- written by Diego Garcia-Gamez, Patrick Green, and Andrzej Szelc
- this model is used for the photon propagation simulation inside the active volume of SBND, and is also used to generate flash hypotheses for charge-light matching

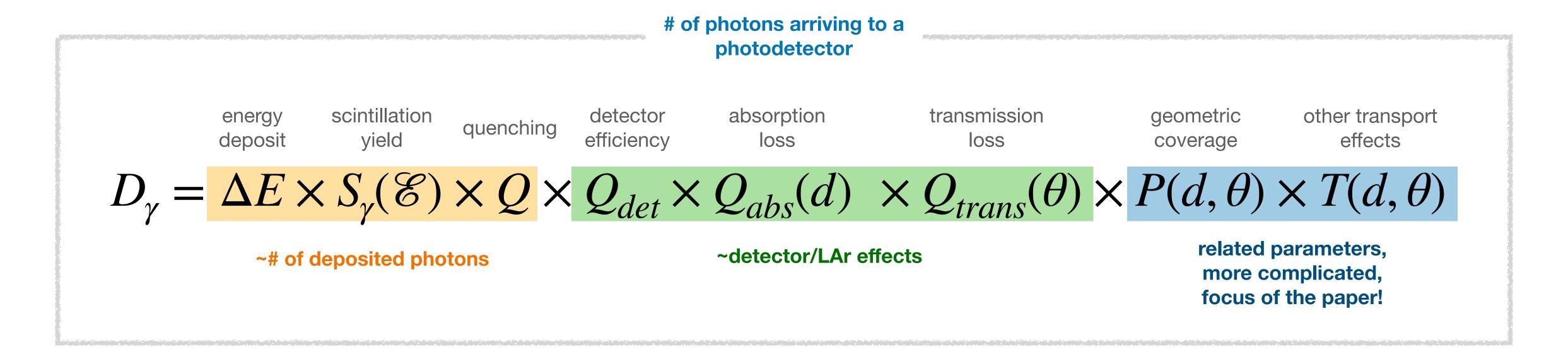


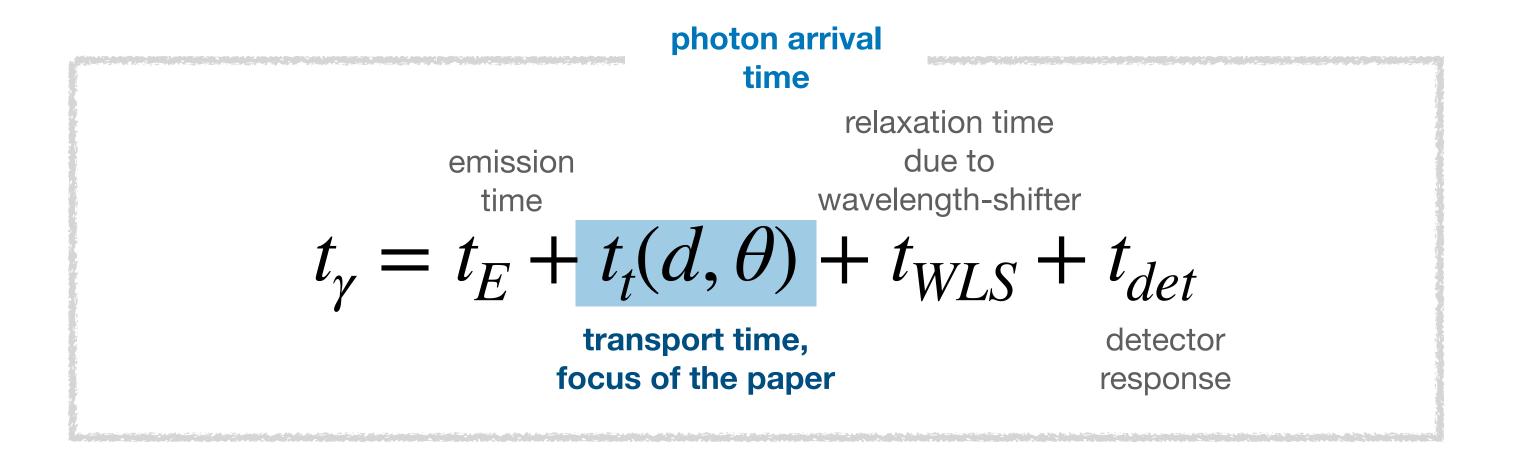
Semi-Analytical Model: tldr;

- "analytical" → the foundation of the photon transport model, for both # of photons and the arrival times, is based on geometric (analytical) functions
- "semi" → corrections are necessary to account for realistic effects, such as Rayleigh scattering, reflection on detector edges, and more
 - corrections are obtained empirically by comparing a full optical simulation with Geant4 with the geometric (analytical) functions
 - corrections are always parametrized by:
 - 1. distance between energy deposition and a photodetector
 - 2. angle between energy deposition and a photodetector



Generic Model for Photon Propagation









Direct (VUV) Light

• ideal case: # of photons arriving at a photodetector (PD) is purely the geometric acceptance of the PD w.r.t. the scintillation point with absorption effects

absorption
$$N_{\Omega}=e^{-\frac{d}{\lambda_{abs}}}\Delta E\cdot S_{\gamma}(\mathcal{E})rac{\Omega}{4\pi}$$
 # of photons

- corrections are needed to this ideal geometric case due to:
 - Rayleigh scattering aka photon scattering → corrected by Gaisser-Hillas (GH) functions, which happen to accurately describe the distributions
 - 2. detector edge effects \rightarrow linear corrections to the GH functions
- the form and parameters of the corrections are obtained by empirically comparing the photon model to a full Geant4 optical simulation

Reflected (VIS) Light

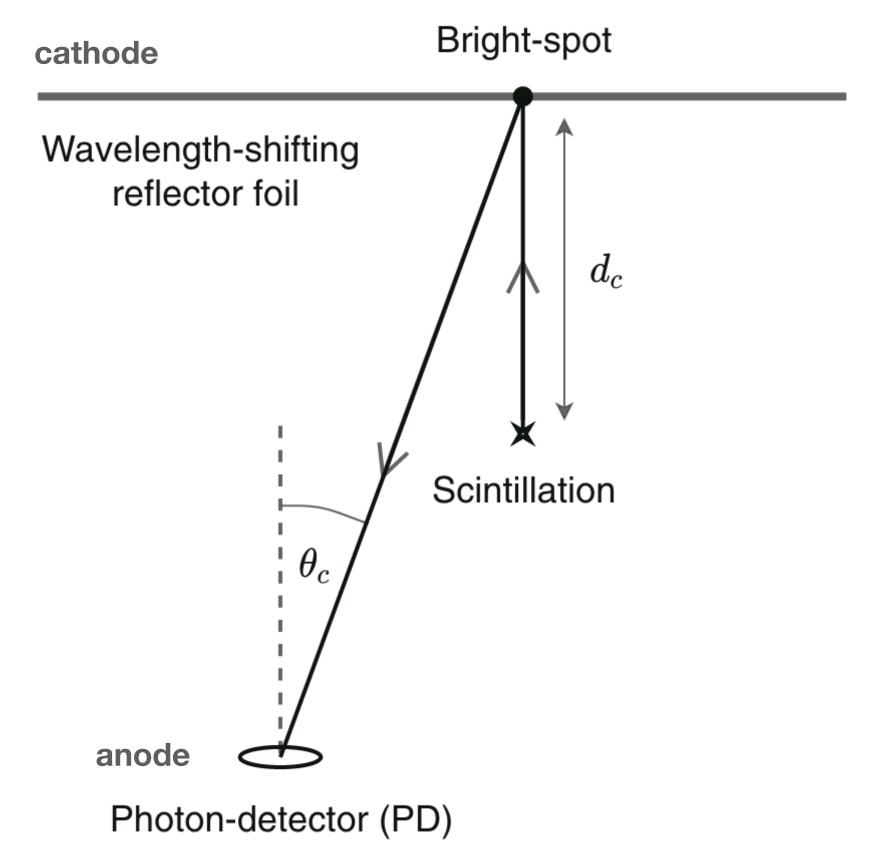


Fig. 8 Diagram illustrating the geometric model for predicting the number of photons incident on the PDs as a result of wavelength-shifting reflector foils on the detector cathode and predicting the arrival time distribution of these photons on the PDs

- in this case, reflected light means **light that was re-emitted/reflected by the cathode**, which is covered WLS-coated reflector foils (wavelength shifter)
- photons are re-emitted ~isotropically, so the source of photons is approximately the "bright-spot" on the cathode ... + corrections
 - # of reflected photons purely from geometry:

$$N_{\Omega,reflected} = N_{\gamma,direct} imes Q_r imes rac{\Omega_{PD}}{2\pi}$$
 # of VUV photons incident on the **cathode**

Reflected (VIS) Light + Corrections

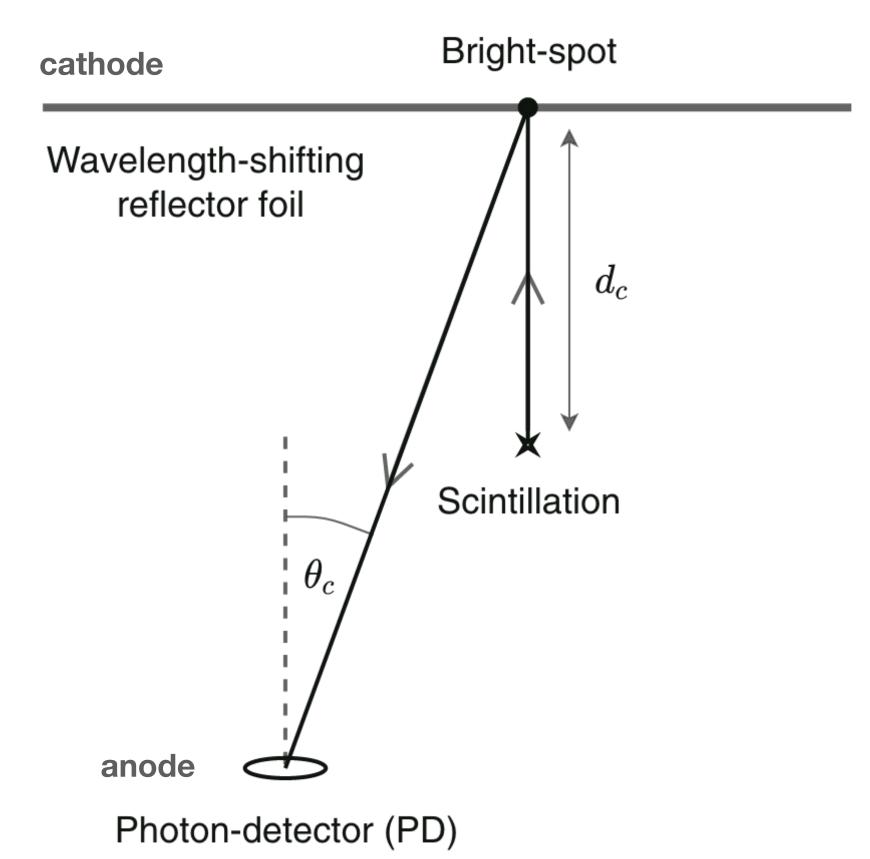
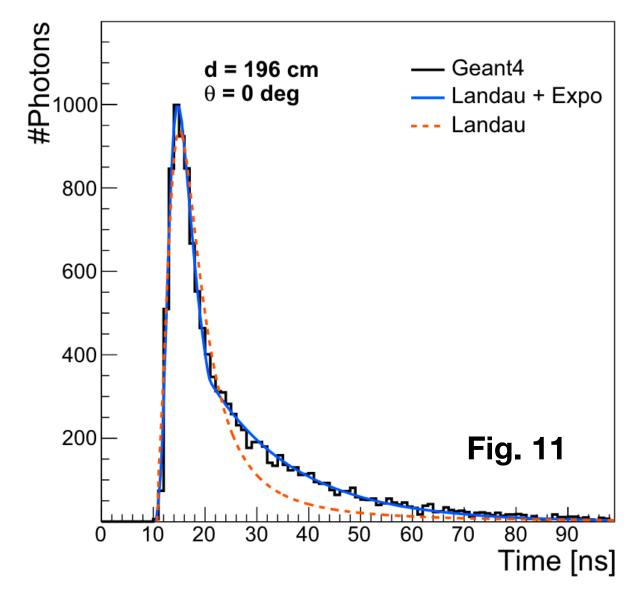


Fig. 8 Diagram illustrating the geometric model for predicting the number of photons incident on the PDs as a result of wavelength-shifting reflector foils on the detector cathode and predicting the arrival time distribution of these photons on the PDs

- 1. additional geometric corrections (PD position)
- 2. detector edge effects
 - VIS photons have slightly different effects (reflection vs. absorption on detector walls) compared to VUV
- all corrections are dependent on d_c and θ_c , obtained from comparing N_{G4} (from simulation) vs. N_{Ω} (geometric)

Photon Arrival Time: Direct (VUV) light

- generically, there will be a prompt component followed by a diffuse tail
 - prompt: earliest photons that arrive
 - tail: photons w/ other transport effects (reflection, re-emission for VIS, scattering)
- direct (VUV) parametrization: empirically determined to be approximately a Landau function (prompt) combined with an exponential function (tail) functions



$$t_t(x) = N_1 \frac{1}{\xi} \frac{1}{2\pi i} \int_{c-i\infty}^{c+i\infty} e^{\lambda s + s \log s} ds + N_2 e^{\kappa x}$$
Landau exponential

Photon Arrival Time: Reflected (VIS) light

- reflected (VIS) light time parametrization
 - detector walls are highly reflective for visible photons
 - a smearing factor is implemented to account for the broader distribution of photons arriving later

unsmeared smearing factor arrival time
$$t_S = t + (t - t_f) \cdot [e^{-\tau \ln(x)} - 1]$$
 smeared fastest arrival time arrival time

Implementation in Charge-Light Matching

```
void PhotonLibHypothesis::FillEstimateSemiAnalytical(const QCluster_t& trk, Flash_t &flash) const
 for ( size_t ipt = 0; ipt < trk.size(); ++ipt) {
   auto const& pt = trk[ipt];
   geo::Point_t const xyz = {pt.x, pt.y, pt.z};
   double n_original_photons = pt.q;
   std::vector<double> direct_visibilities;
   _semi_model->detectedDirectVisibilities(direct_visibilities, xyz);
   std::vector<double> reflected_visibilities;
   _semi_model->detectedReflectedVisibilities(reflected_visibilities, xyz);
    for (size_t op_det=0; op_det<direct_visibilities.size(); ++op_det) {</pre>
     const double visibility = direct_visibilities[op_det];
     double q = n_original_photons * visibility * _global_qe * _qe_v[op_det];
     if (trk.tpc_mask_v.at(op_det) == 0)
        flash.pe_v[op_det] += q;
     else
        flash.pe_v[op_det] = 0.;
                                                    SBND light hypothesis generation: code link
```

 for charge-light matching, the arrival times are not too important, but the # of predicted/measured photons is!

• the model returns a *visibility* map depending on a geometric position

$$N_{\gamma,PD} = N_{\gamma} \cdot \mathrm{vis} \cdot Q_{eff}$$

Summary

- I gave an overview of the photon propagation model used in SBND
- the paper covers model validation and performance for SBND-like and DUNE-like detector geometries

- Diego has confirmed that it is possible to make the code for the photon model standalone (separate from LArSoft implementation, thanks Ewerton!)
- I can also answer questions about flash-matching in SBND, which uses a similar methodology to WireCell charge-light matching